# 2SD1272

### Silicon NPN epitaxial planar type

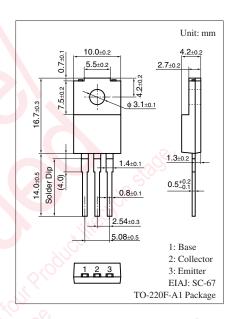
For high-speed switching and high current amplification ratio

#### ■ Features

- $\bullet$  High forward current transfer ratio  $h_{FE}$
- $\bullet$  Satisfactory linearity of forward current transfer ratio  $h_{\text{FE}}$
- Full-pack package which can be installed to the heat sink with one screw

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	200	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	150	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	6	V	
Collector current	$I_C$	2.5	A	
Peak collector current	$I_{CP}$	1	A	
Collector power $T_C = 25^{\circ}C$	$P_{C}$	40	W	
dissipation		2.0		
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	



### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

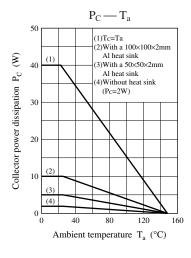
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_C = 25 \text{ mA}, I_B = 0$	150	0,		V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 200 \text{ V}, I_E = 0$		0.	100	μΑ
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 6 \text{ V}, I_{C} = 0$	1.90		100	μΑ
Forward current transfer ratio *	$h_{FE}$	$V_{CE} = 4 \text{ V}, I_{C} = 0.2 \text{ A}$	500		2000	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 0.5 \text{ A}, I_B = 0.02 \text{ A}$			1	V
Transition frequency	$f_T$	$V_{CE} = 4 \text{ V}, I_{C} = 0.1 \text{ A}, f = 10 \text{ MHz}$		25		MHz

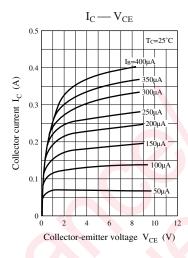
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

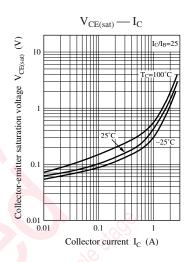
#### 2. \*: Rank classification

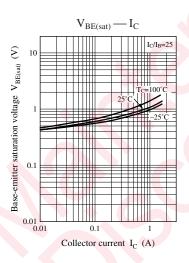
Rank	Q	Р
$h_{FE}$	500 to 1 200	800 to 2000

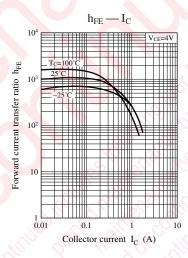
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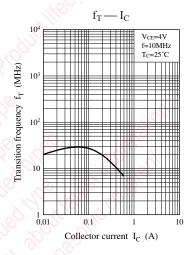


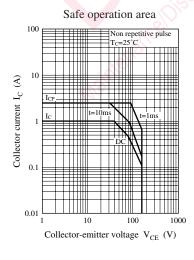


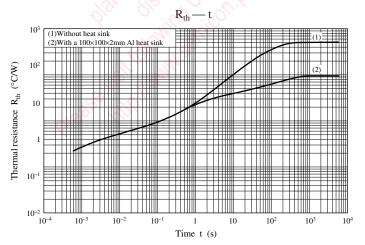












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